**Vishay High Power Products** 

## **Phase Control Thyristors** (Hockey PUK Version), 960 A

### **FEATURES**

- Center amplifying gate
- · Metal case with ceramic insulator
- International standard case TO-200AB (E-PUK)
- Extended temperature range
- · Low profile hockey PUK to increase current-carrying capability
- · Lead (Pb)-free
- · Designed and qualified for industrial level

#### **TYPICAL APPLICATIONS**

- · DC motor controls
- · Controlled DC power supplies
- AC controllers

MAJOR RATINGS AND CHARACTERISTICS						
PARAMETER	TEST CONDITIONS	VALUES	UNITS			
		960	А			
I <sub>T(AV)</sub>	T <sub>hs</sub>	80	°C			
		2220	А			
I <sub>T(RMS)</sub>	T <sub>hs</sub>	25	°C			
I <sub>TSM</sub>	50 Hz	12 500	A			
	60 Hz	13 000	A			
l <sup>2</sup> t	50 Hz	782	kA <sup>2</sup> s			
	60 Hz	713	KA-5			
V <sub>DRM</sub> /V <sub>RRM</sub>		400 to 600	V			
tq	Typical	100	μs			
TJ		- 40 to 150	°C			

#### **ELECTRICAL SPECIFICATIONS**

VOLTAGE R	ATINGS			
TYPE NUMBER	VOLTAGE CODE	V <sub>DRM</sub> /V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	$I_{DRM}/I_{RRM}$ MAXIMUM AT T <sub>J</sub> = T <sub>J</sub> MAXIMUM mA
ST380CHC	04	400	500	100
01000010	06	600	700	100





COMPLIANT





TO-200AB (E-PUK)

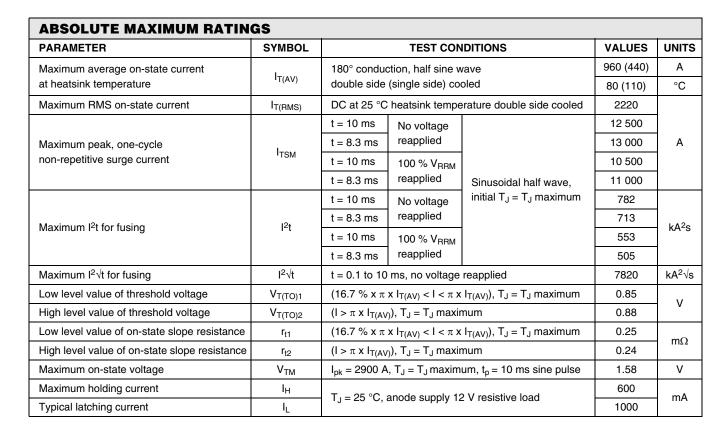
960 A

**PRODUCT SUMMARY** 

I<sub>T(AV)</sub>

## ST380CHPbF Series

#### Vishay High Power Products Phase Control Thyristors (Hockey PUK Version), 960 A



SWITCHING							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum non-repetitive rate of rise of turned-on current	dl/dt	Gate drive 20 V, 20 $\Omega,  t_r \leq$ 1 $\mu s$ $T_J$ = $T_J$ maximum, anode voltage $\leq$ 80 % $V_{DRM}$	1000	A/µs			
Typical delay time	t <sub>d</sub>	Gate current 1 A, dl <sub>g</sub> /dt = 1 A/ $\mu$ s V <sub>d</sub> = 0.67 % V <sub>DRM</sub> , T <sub>J</sub> = 25 °C	1.0				
Typical turn-off time	tq	$I_{TM}$ = 550 A, T <sub>J</sub> = T <sub>J</sub> maximum, dl/dt = 40 A/μs, V <sub>R</sub> = 50 V, dV/dt = 20 V/μs, gate 0 V 100 Ω, t <sub>p</sub> = 500 μs	100	μs			

BLOCKING								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum linear to 80 % rated $V_{DRM}$	500	V/µs				
Maximum peak reverse and off-state leakage current	I <sub>RRM</sub> , I <sub>DRM</sub>	$T_J = T_J$ maximum, rated $V_{DRM}/V_{RRM}$ applied	100	mA				



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TRIGGERING						
PARAMETER	SYMBOL				VALUES	
PARAMEIER	STMBOL	SYMBOL TEST CONDITIONS		TYP.	MAX.	UNITS
Maximum peak gate power	P <sub>GM</sub>	$T_J = T_J$ maximum,	$t_p \le 5 ms$	10.0		w
Maximum average gate power	P <sub>G(AV)</sub>	$T_J = T_J$ maximum,	f = 50 Hz, d% = 50	2	.0	vv
Maximum peak positive gate current	I <sub>GM</sub>	$T_J = T_J$ maximum,	$t_p \leq 5 ms$	3	.0	А
Maximum peak positive gate voltage	+ V <sub>GM</sub>		t < 5 mc	20		v
Maximum peak negative gate voltage	- V <sub>GM</sub>	$T_J = T_J$ maximum, $t_p \le 5$ ms			5.0	
		T <sub>J</sub> = - 40 °C		200	-	
DC gate current required to trigger	I <sub>GT</sub>	T <sub>J</sub> = 25 °C	Maximum required gate trigger/ current/voltage are the lowest	100	200	mA
		T <sub>J</sub> = 150 °C		40	-	
		T <sub>J</sub> = - 40 °C	value which will trigger all units	2.5	-	
DC gate voltage required to trigger	V <sub>GT</sub>	T <sub>J</sub> = 25 °C	12 V anode to cathode applied	1.8	3.0	V
		T <sub>J</sub> = 150 °C		1.0	-	
DC gate current not to trigger	I <sub>GD</sub>		Maximum gate current/voltage not to trigger is the maximum	1	0	mA
DC gate voltage not to trigger	V <sub>GD</sub>	$T_J = T_J maximum$	value which will not trigger any unit with rated V <sub>DRM</sub> anode to cathode applied	0.25		v

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS		UNITS		
Maximum operating junction temperature range	TJ		40 to 150	ე∘		
Maximum storage temperature range	T <sub>Stg</sub>		- 40 to 150	-0		
Maximum thermal registeries, junction to besteink	P	DC operation single side cooled	0.09			
Maximum thermal resistance, junction to heatsink	R <sub>thJ-hs</sub>	DC operation double side cooled	0.04	К/W		
•• • • • • • • • • • • •	R <sub>thC-hs</sub>	DC operation single side cooled	0.02			
Maximum thermal resistance, case to heatsink		DC operation double side cooled	0.01			
Mounting force, ± 10 %			9800 (1000)	N (kg)		
Approximate weight			83	g		
Case style		See dimensions - link at the end of datasheet	TO-200AB (8	E-PUK)		

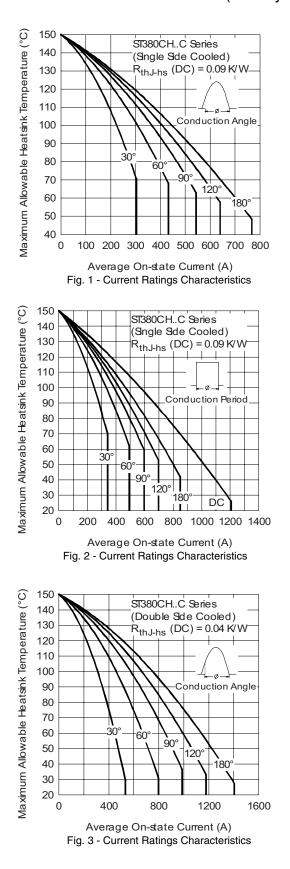
CONDUCTION ANGLE	SINUSOIDAL	CONDUCTION	RECTANGULAR CONDUCTION		TEST CONDITIONS	UNITS		
CONDUCTION ANGLE	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE	TEST CONDITIONS			
180°	0.010	0.011	0.007	0.007				
120°	0.012	0.012	0.012	0.013				
90°	0.015	0.015	0.016	0.017	$T_J = T_J$ maximum	K/W		
60°	0.022	0.022	0.023	0.023				
30°	0.036	0.036	0.036	0.037				

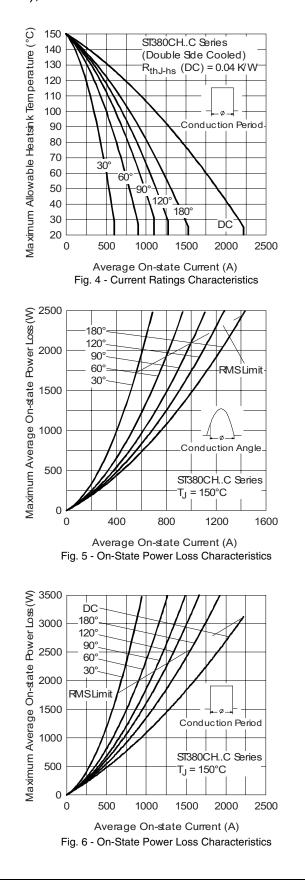
Note

• The table above shows the increment of thermal resistance R<sub>thJ-hs</sub> when devices operate at different conduction angles than DC

## ST380CHPbF Series

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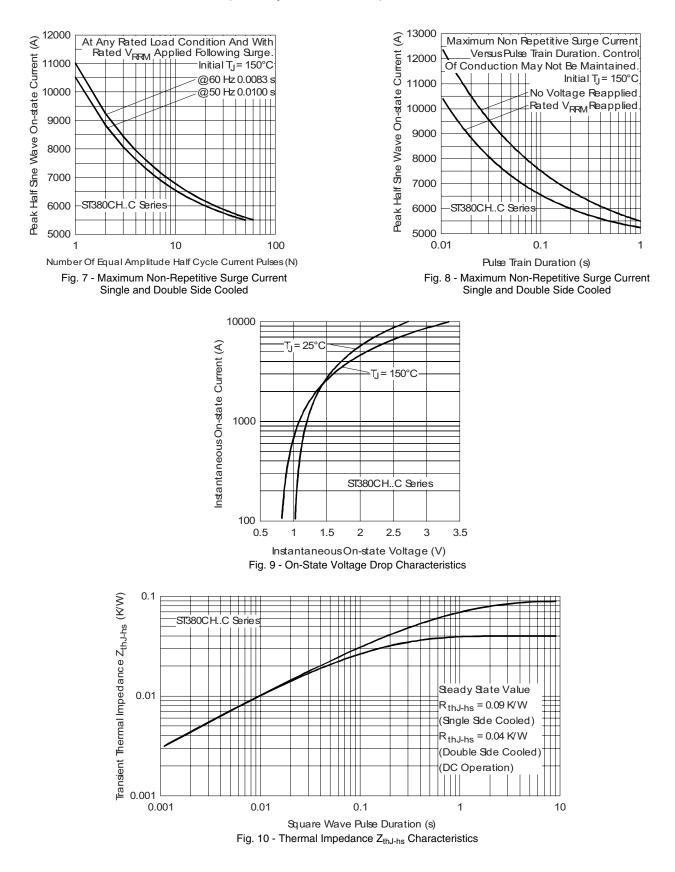






Phase Control Thyristors Vishay (Hockey PUK Version), 960 A

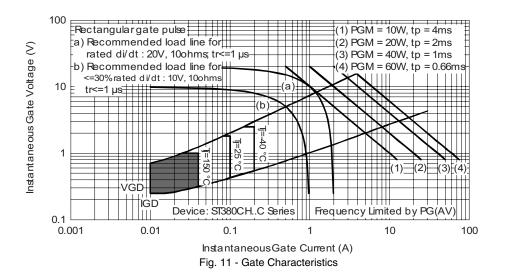
Vishay High Power Products



### **ST380CHPbF Series**



#### Vishay High Power Products Phase Control Thyristors (Hockey PUK Version), 960 A



#### **ORDERING INFORMATION TABLE**

Device code	ST	38	0	СН	06	С	1	-	PbF	
	1	2	3	4	5	6	(7)	8	9	
	1 - 2 - 3 - 4 - 5 - 6 - 7 -	<ul> <li>Ess</li> <li>0 =</li> <li>CH</li> <li>Volt</li> <li>C =</li> </ul>	rristor ential pa Conver = Cerar tage coo PUK ca Eyelet t	ter grad nic PUK de x 100 ase TO-2	e K, high te = V <sub>RRN</sub> 200AB (	<sub>1</sub> (see V E-PUK)	oltage F		table) insoldered le	ads)
	8 -	2 = 3 = - Crit	Eyelet t	erminals termina dt: • No • L =	s (gate a Ils (gate	and aux and au 0 V/µs (	iliary ca xiliary c (standai	thode s athode rd selec		s)

LINKS TO RELATED DOCUMENTS						
Dimensions	http://www.vishay.com/doc?95075					

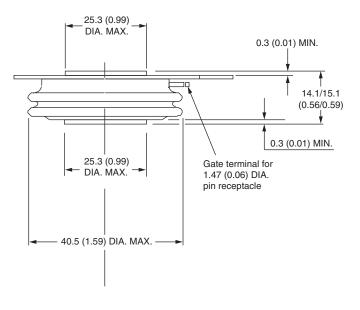


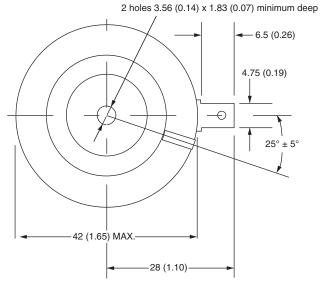
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### TO-200AB (E-PUK)

#### **DIMENSIONS** in millimeters (inches)

Anode to gate Creepage distance: 11.18 (0.44) minimum Strike distance: 7.62 (0.30) minimum





Quote between upper and lower pole pieces has to be considered after application of mounting force (see thermal and mechanical specification)



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